

## 8/16-bit Data Bus Static RAM Card

Connector Type

**Two-piece 68-pin**

**MF365A-J9CATXX**

**MF3129-J9CATXX**

**MF3257-J9CATXX**

**MF3513-J9CATXX**

**MF31M1-J9CATXX**

**MF32M1-J9CATXX**

**MF34M1-J9CATXX**

### 1. DESCRIPTION

Mitsubishi's Static RAM cards provide large memory capacities on a device approximately the size of a credit card (85.6mm×54mm×3.3mm). The cards use a 8/16 bit data-bus.

Available in 64KB, 128KB, 256KB, 512KB, 1 MB, 2 MB and 4 MB capacities, Mitsubishi's SRAM cards conform to the PC Card Standard. Mitsubishi achieved high density memory, while maintaining credit size by using a thin small outline packaging technology (TSOP). The TSOP surpasses conventional memory card chip-on-board packaging technology where larger, surface-mount devices result in a tradeoff between card size and optimum memory density. The TSOP, with external leads spaced on 20-mil centers, is over four times smaller than standard equivalent pin count surface-mount packages. This allows up to 8 memory ICs (plus interface circuitry) to be mounted in a card that in only 3.3mm thick.

### 2. FEATURES

- Uses TSOP (Thin Small Outline Package) to achieve very high memory density coupled with high reliability, without enlarging card size
- Electrostatic discharge protection to 15kV
- Buffered interface
- Write protect switch
- 68pin
- Built-in auxiliary battery

### 3. APPLICATIONS

- Office automation
- Data Communication
- Computers
- Industrial
- Telecommunications
- Consumer

### 4. PRODUCT LIST

| Type name \ Item | Memory capacity | Data Bus width(bits) | Attribute memory | Auxiliary battery |
|------------------|-----------------|----------------------|------------------|-------------------|
| MF365A-J9CATXX   | 64KB            | 8/16                 | NO               | YES               |
| MF3129-J9CATXX   | 128KB           |                      |                  |                   |
| MF3257-J9CATXX   | 256KB           |                      |                  |                   |
| MF3513-J9CATXX   | 512KB           |                      |                  |                   |
| MF31M1-J9CATXX   | 1MB             |                      |                  |                   |
| MF32M1-J9CATXX   | 2MB             |                      |                  |                   |
| MF34M1-J9CATXX   | 4MB             |                      |                  |                   |



## 5. SUMMARY

MF3XXX-J9CATXX series is the Static RAM cards which has 8/16 bit changeable data-bus width. The card has a replaceable lithium main battery to maintain data in memory and has an auxiliary battery to maintain data in memory while the main battery is replaced. When the card is not use or the supply voltage drops, the main battery will automatically maintain data in memory.

## 6. FUNCTIONAL DESCRIPTION

The function of the card is determined by the combination of the following five control signals, REG#, CE1#, CE2#, OE#, WE#; active low signals. (Please refer to section 10 FUNCTION TABLE on page 5)

### (1)COMMON MEMORY FUNCTION

When REG# signal is high level, the common memory area is selected.

#### (a)READ MODE

To read, WE# is set high level and CE1# or CE2# is set low level and the memory address is applied at inputs A0-A21(4MB). Setting OE# low level executes the reading with output at data-bus. It is available to make the following functions according to the combination of CE1# and CE2#.

When CE1# is set low level and CE2# is set high level, the card operates as an 8 bit data-bus width card.

The data can be dealt with lower data-bus(D0-D7).

When both CE1# and CE2# are set low level, the card operates as a 16 bit data-bus width card.

At this mode LSB of address-bus (A0) is ignored.

In addition odd byte can be accessed through upper data-bus(D8-D15) when CE1# is set high level and CE2# is set low level. This mode is useful when handling only odd bytes in the 16 bit data-bus interface system (A0 is ignored).

When both CE1# and CE2# are set high level, the card becomes a standby mode where the card consumes low power and the data-bus is placed in high impedance state (above functions of CE1# and CE2# are the same as in the following modes).

When both OE# and WE# are set high level, the card becomes a output disable mode and the data-bus is placed in high impedance state.

#### (b)WRITE MODE

To write, the memory address is first applied at inputs A0-A21(4MB) and the data is applied at output pins. Setting CE1# or CE2# low level, WE# low level and OE# high level executes the writing.

### (2)ATTRIBUTE MEMORY FUNCTION

When REG# is set low level, the attribute memory area is selected. MF3XXX-J9CATXX series have no attribute memory but outputs FFh on the lower data-bus(D0-D7) when the following conditions are applied

(a)setting CE1# low, CE2# high, OE# low, WE# high and A0 low

(b)setting CE1# low, CE2# low, OE# low and WE# high

### (3)BATTERY

When the card is used for long periods of time, eventually battery exhaustion occurs. If such a situation is encountered, replace any exhausted battery with a new one as directed in section 21.2 "REPLACING BATTERY" (page 14).

The replacement battery model number is indicated under section 21 "BATTERY SPECIFICATIONS"(page 14).

## 7. WRITE PROTECT MODE

When the write protect switch is switched on, this card goes into a write protect mode that can read but not write data. In this mode, WP pin becomes "H" level.

At the shipment the write protect switch is switched off (Normal mode : The card can be written ; WP pin indicates "L" level).

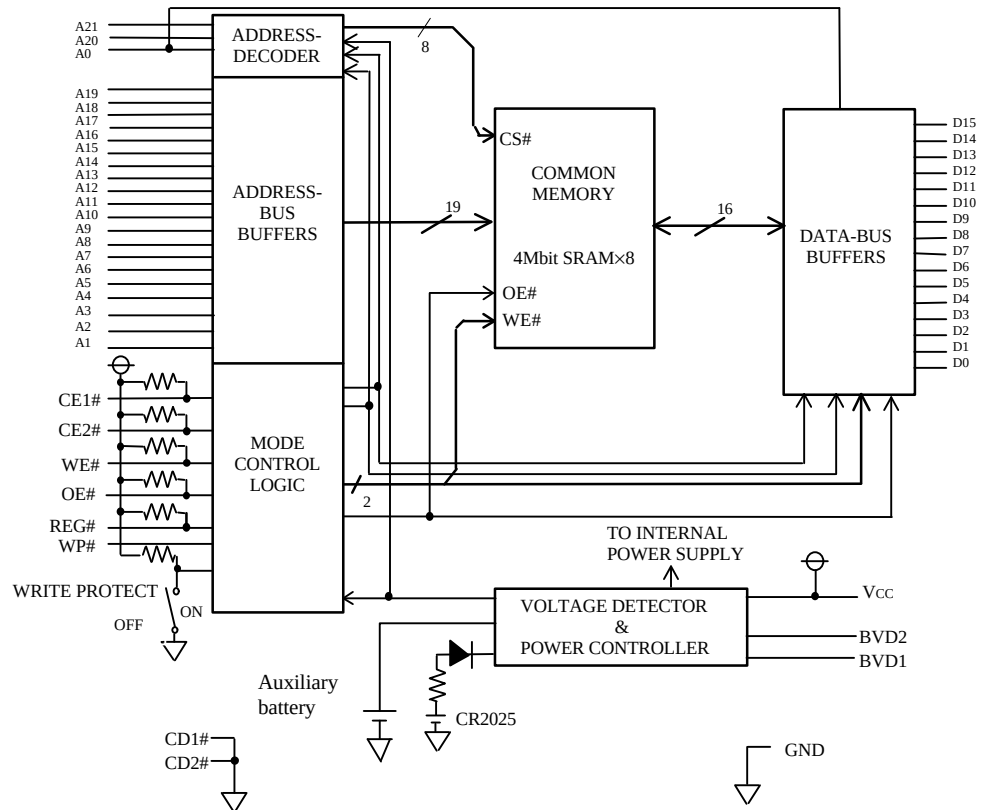


# 8. PIN ASSIGNMENTS

| Pin No. | Symbol | Function               | Pin No. | Symbol | Function                               |
|---------|--------|------------------------|---------|--------|----------------------------------------|
| 1       | GND    | Ground                 | 35      | GND    | Ground                                 |
| 2       | D3     | Data I/O               | 36      | CD1#   | Card detect 1                          |
| 3       | D4     |                        | 37      | D11    | Data I/O                               |
| 4       | D5     |                        | 38      | D12    |                                        |
| 5       | D6     |                        | 39      | D13    |                                        |
| 6       | D7     |                        | 40      | D14    |                                        |
| 7       | CE1#   | Card enable 1          | 41      | D15    |                                        |
| 8       | A10    | Address input          | 42      | CE2#   | Card enable 2                          |
| 9       | OE#    | Output enable          | 43      | NC     | No connection                          |
| 10      | A11    | Address input          | 44      | NC     |                                        |
| 11      | A9     |                        | 45      | NC     |                                        |
| 12      | A8     |                        | 46      | A17    | A17 (NC for $\leq 128\text{KB}$ types) |
| 13      | A13    |                        | 47      | A18    | A18 (NC for $\leq 256\text{KB}$ types) |
| 14      | A14    |                        | 48      | A19    | A19 (NC for $\leq 512\text{KB}$ types) |
| 15      | WE#    | Write enable           | 49      | A20    | A20 (NC for $\leq 1\text{MB}$ type)    |
| 16      | NC     | No connection          | 50      | A21    | A21 (NC for $\leq 2\text{MB}$ type)    |
| 17      | VCC    | Power supply voltage   | 51      | VCC    | Power supply voltage                   |
| 18      | NC     | No connection          | 52      | NC     | No connection                          |
| 19      | A16    | A16 (NC for 64KB type) | 53      | NC     |                                        |
| 20      | A15    | Address input          | 54      | NC     |                                        |
| 21      | A12    |                        | 55      | NC     |                                        |
| 22      | A7     |                        | 56      | NC     |                                        |
| 23      | A6     |                        | 57      | NC     |                                        |
| 24      | A5     |                        | 58      | NC     |                                        |
| 25      | A4     |                        | 59      | NC     |                                        |
| 26      | A3     |                        | 60      | NC     |                                        |
| 27      | A2     |                        | 61      | REG#   | Attribute memory select                |
| 28      | A1     |                        | 62      | BVD2   | Battery voltage detect 2               |
| 29      | A0     | Data I/O               | 63      | BVD1   | Battery voltage detect 1               |
| 30      | D0     |                        | 64      | D8     | Data I/O                               |
| 31      | D1     |                        | 65      | D9     |                                        |
| 32      | D2     |                        | 66      | D10    |                                        |
| 33      | WP     | Write protect          | 67      | CD2#   | Card detect 2                          |
| 34      | GND    | Ground                 | 68      | GND    | Ground                                 |



9. BLOCK DIAGRAM (4MB) (MF34M1-J9CATXX)



# 10. FUNCTION TABLE

| Mode                     | REG# | CE1# | CE2# | OE# | WE# | A0 | I/O (D15~D8)       | I/O (D7~D0)        | Icc     |
|--------------------------|------|------|------|-----|-----|----|--------------------|--------------------|---------|
| Standby                  | X    | H    | H    | X   | X   | X  | High-impedance     | High-impedance     | standby |
| Read A (16bit) common    | H    | L    | L    | L   | H   | X  | Odd Byte Data out  | Even Byte Data out | Active  |
| Write A (16bit) common   | H    | L    | L    | H   | L   | X  | Odd Byte Data in   | Even Byte Data in  | Active  |
| Read B (8bit) common     | H    | L    | H    | L   | H   | L  | High-impedance     | Even Byte Data out | Active  |
|                          | H    | L    | H    | L   | H   | H  | High-impedance     | Odd Byte Data out  | Active  |
| Write B (8bit) common    | H    | L    | H    | H   | L   | L  | High-impedance     | Even Byte Data in  | Active  |
|                          | H    | L    | H    | H   | L   | H  | High-impedance     | Odd Byte Data in   | Active  |
| Read C (8bit) common     | H    | H    | L    | L   | H   | X  | Odd Byte Data out  | High-impedance     | Active  |
| Write C (8bit) common    | H    | H    | L    | H   | L   | X  | Odd Byte Data in   | High-impedance     | Active  |
| Output disable           | X    | X    | X    | H   | H   | X  | High-impedance     | High-impedance     | Active  |
| Read A (16bit) attribute | L    | L    | L    | L   | H   | X  | Data out (unknown) | Data out (FFh)     | Active  |
| Read B (8bit) attribute  | L    | L    | H    | L   | H   | L  | High-impedance     | Data out (FFh)     | Active  |
|                          | L    | L    | H    | L   | H   | H  | High-impedance     | Data out (unknown) | Active  |
| Read C (8bit) attribute  | L    | H    | L    | L   | H   | X  | Data out (unknown) | High-impedance     | Active  |

Note 1 : H=V<sub>IH</sub>, L=V<sub>IL</sub>, X=V<sub>IH</sub> or V<sub>IL</sub>

# 11. ABSOLUTE MAXIMUM RATINGS

| Symbol            | Parameter               | Conditions              | Ratings                   | Unit |
|-------------------|-------------------------|-------------------------|---------------------------|------|
| V <sub>CC</sub>   | Supply voltage          | With respect to GND     | -0.3~6.0                  | V    |
| V <sub>I</sub>    | Input voltage           |                         | -0.3~V <sub>CC</sub> +0.3 | V    |
| V <sub>O</sub>    | Output voltage          |                         | 0~V <sub>CC</sub>         | V    |
| T <sub>opr1</sub> | Operating temperature 1 | Read, Write Operation   | 0~60                      | °C   |
| T <sub>opr2</sub> | Operating temperature 2 | Data retention          | 0~60                      | °C   |
| T <sub>stg</sub>  | Storage temperature     | Excludes data retention | -20~70                    | °C   |

# 12. RECOMMENDED OPERATING CONDITIONS (Ta=0~55°C, unless otherwise noted)

| Symbol          | Parameter                      | Limits |      |                 | Unit |
|-----------------|--------------------------------|--------|------|-----------------|------|
|                 |                                | Min.   | Typ. | Max.            |      |
| V <sub>CC</sub> | V <sub>CC</sub> Supply voltage | 4.75   | 5.0  | 5.25            | V    |
| GND             | System ground                  |        | 0    |                 | V    |
| V <sub>IH</sub> | High input voltage             | 2.4    |      | V <sub>CC</sub> | V    |
| V <sub>IL</sub> | Low input voltage              | 0      |      | 0.8             | V    |



STATIC RAM CARDS

**13. ELECTRICAL CHARACTERISTICS** (Ta=0~55°C, Vcc=5V±5%, unless otherwise noted)

| Symbol    | Parameter                        | Test conditions                                                   |                            | Limits |      |                | Unit |
|-----------|----------------------------------|-------------------------------------------------------------------|----------------------------|--------|------|----------------|------|
|           |                                  |                                                                   |                            | Min.   | Typ. | Max.           |      |
| VOH       | High output voltage              | IOH= -1.0mA                                                       |                            | 2.4    |      |                | V    |
| VOL       | Low output voltage               | IOL=2mA                                                           |                            |        |      | 0.4            | V    |
| IiH       | High input current               | Vi=Vcc V                                                          |                            |        |      | 10             | µA   |
| IiL       | Low input current                | Vi=0V                                                             | CE1#, CE2#, WE#, OE#, REG# | -10    |      | -70            | µA   |
|           |                                  |                                                                   | Other inputs               |        |      | -10            |      |
| IOZH      | High output current in off state | CE1#=CE2#=VIH or OE#=VIH WE#=VIH, Vo=Vcc                          |                            |        |      | 10             | µA   |
| IOZL      | Low output current in off state  | CE1#=CE2#=VIH or OE#=VIH WE#=VIH, Vo=0V                           |                            |        |      | -10            | µA   |
| Icc 1 • 1 | Active supply current 1          | CE1#=CE2#=VIL, other inputs =VIH or VIL, Outputs=open             | 64KB~512KB                 |        |      | 170            | mA   |
|           |                                  |                                                                   | 1MB~4MB                    |        |      | 230            |      |
| Icc 1 • 2 | Active supply current 2          | CE1#=CE2# ≤ 0.2V, other inputs ≤ 0.2V or ≥ Vcc-0.2V, Outputs=open | 64KB~512KB                 |        |      | 160            | mA   |
|           |                                  |                                                                   | 1MB~4MB                    |        |      | 220            |      |
| Icc 2 • 1 | Standby supply current 1         | CE1#=CE2#=VIH other inputs=VIH or VIL                             | 64KB~4MB                   |        |      | 10<br>(17)     | mA   |
| Icc 2 • 2 | Standby supply current 2         | CE1#=CE2# ≥ Vcc-0.2V other inputs ≤ 0.2V or ≥ Vcc-0.2V            | 64KB~512KB                 |        |      | 0.45<br>(7.45) | mA   |
|           |                                  |                                                                   | 1MB~4MB                    |        |      | 0.65<br>(7.65) |      |
| VBDET1    | Battery detect reference voltage | Vcc=5V, Ta=25°C                                                   |                            | 2.27   | 2.37 | 2.47           | V    |
| VBDET2    | Battery detect reference voltage | Vcc=5V, Ta=25°C                                                   |                            | 2.55   | 2.65 | 2.75           | V    |

Note 2 : Currents flowing into the card are taken as positive (unsigned).

3 : Typical values are measured at Vcc=5V, Ta=25°C.

4 : The figure in the parentheses indicates the standby current limits when the built-in auxiliary battery is not fully charged.

**14. CAPACITANCE**

| Symbol | Parameter          | Test conditions                       | Limits |      |      | Unit |
|--------|--------------------|---------------------------------------|--------|------|------|------|
|        |                    |                                       | Min.   | Typ. | Max. |      |
| CI     | Input capacitance  | Vi=GND, vi=25mVrms<br>f=1MHz, Ta=25°C |        |      | 30   | pF   |
| CO     | Output Capacitance | Vo=GND, vo=25mVrms<br>f=1MHz, Ta=25°C |        |      | 20   | pF   |

Note 4 : These parameters are not 100% tested.



## 15. SWITCHING CHARACTERISTICS

**Read Cycle** (Ta=0~55°C, VCC=5V±5%, unless otherwise noted)

| Symbol   | Parameter                              | Limits |      | Unit |
|----------|----------------------------------------|--------|------|------|
|          |                                        | Min.   | Max. |      |
| tcR      | Read cycle time                        | 150    |      | ns   |
| ta(A)    | Address access time                    |        | 150  | ns   |
| ta(CE)   | Card enable access time                |        | 150  | ns   |
| ta(OE)   | Output enable access time              |        | 75   | ns   |
| tdis(CE) | Output disable time (from CE#)         |        | 75   | ns   |
| tdis(OE) | Output disable time (from OE#)         |        | 75   | ns   |
| ten(CE)  | Output enable time (from CE#)          | 5      |      | ns   |
| ten(OE)  | Output enable time (from OE#)          | 5      |      | ns   |
| tv(A)    | Data valid time (after address change) | 0      |      | ns   |

## 16. TIMING REQUIREMENTS

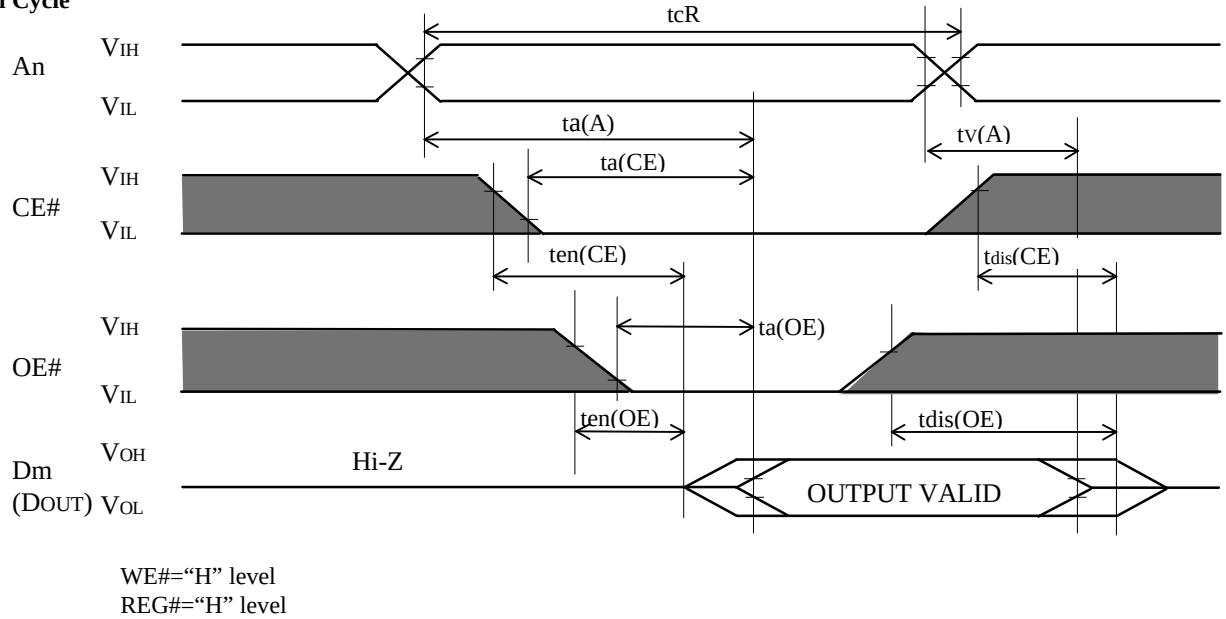
**Write Cycle** (Ta=0~55°C, Vcc=5V±5%, unless otherwise noted)

| Symbol      | Parameter                                        | Limits |      | Unit |
|-------------|--------------------------------------------------|--------|------|------|
|             |                                                  | Min.   | Max. |      |
| tcW         | Write cycle time                                 | 150    |      | ns   |
| tw(WE)      | Write pulse width                                | 80     |      | ns   |
| tsu(A)      | Address set up time                              | 20     |      | ns   |
| tsu(A-WEH)  | Address set up time with respect to WE# high     | 100    |      | ns   |
| tsu(CE-WEH) | Card enable set up time with respect to WE# high | 100    |      | ns   |
| t(D-WEH)    | Data set up time with respect to WE# high        | 50     |      | ns   |
| th(D)       | Data hold time                                   | 20     |      | ns   |
| trec(WE)    | Write recovery time                              | 20     |      | ns   |
| tdis(WE)    | Output disable time (from WE#)                   |        | 75   | ns   |
| tdis(OE)    | Output disable time (from OE#)                   |        | 75   | ns   |
| ten(WE)     | Output enable time (from WE#)                    | 5      |      | ns   |
| ten(OE)     | Output enable time (from OE#)                    | 5      |      | ns   |
| tsu(OE-WE)  | OE# set up time with respect to WE# low          | 10     |      | ns   |
| th(OE-WE)   | OE# hold time with respect to WE# high           | 10     |      | ns   |

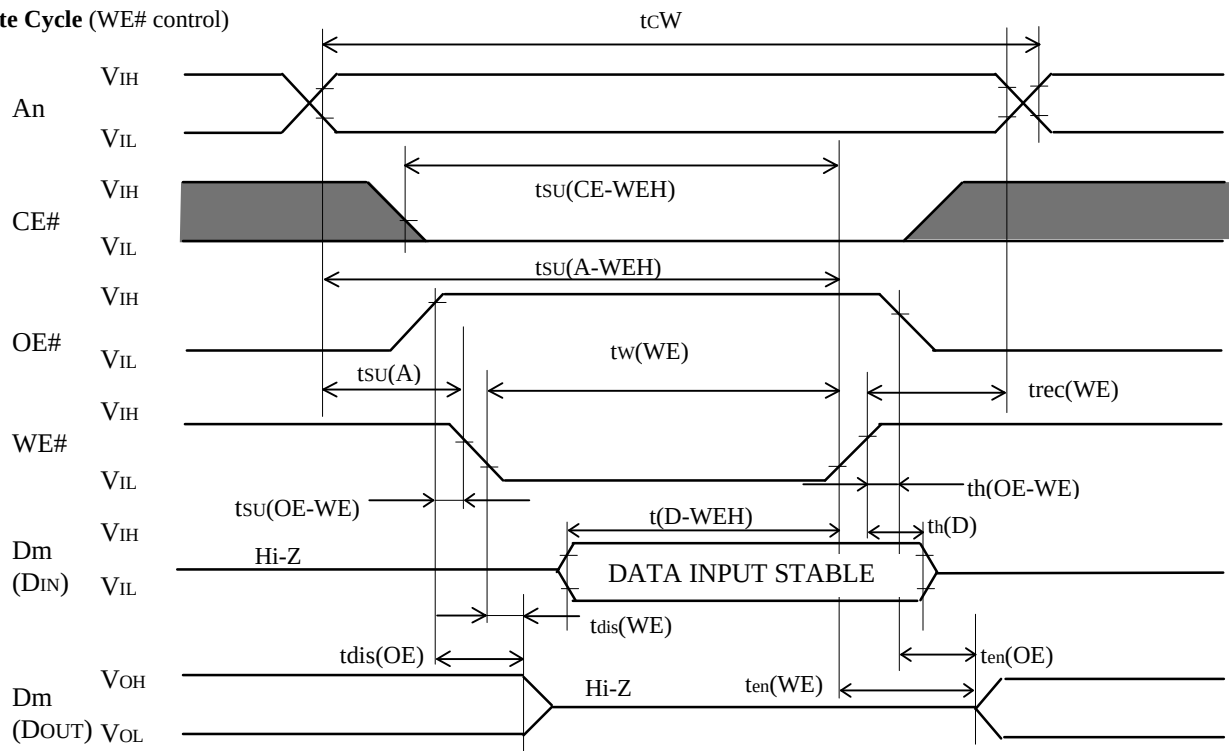


**TIMING DIAGRAM**

**Read Cycle**

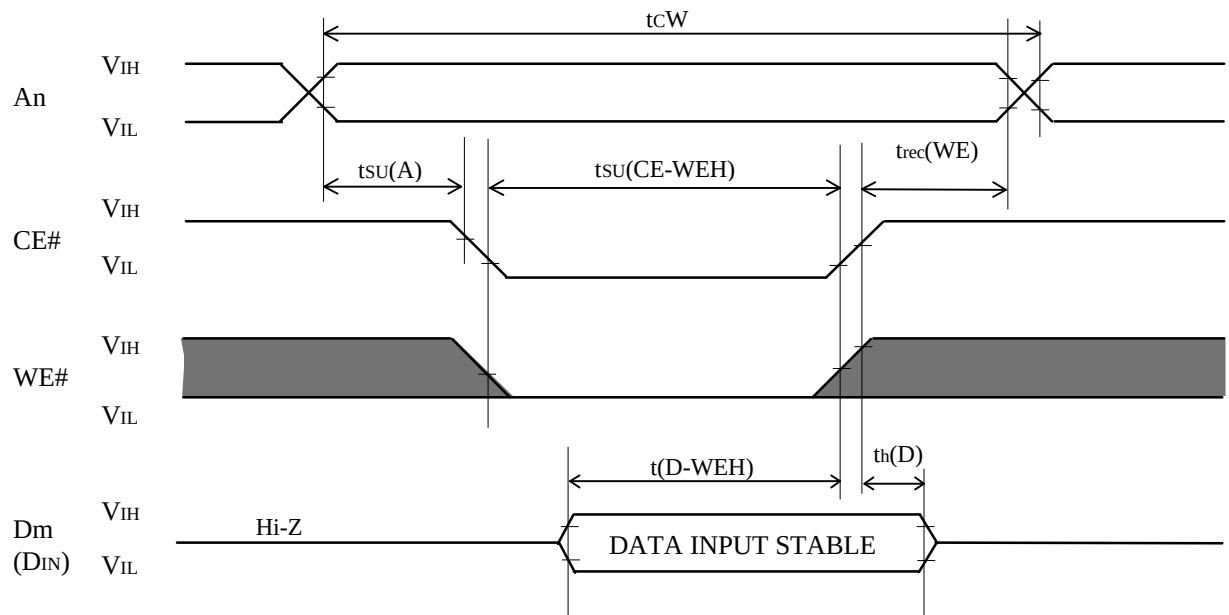


**Write Cycle (WE# control)**





**Write Cycle (CE# control)**



$\text{OE}\# = \text{"H" level}$   
 $\text{REG}\# = \text{"H" level}$

**17. SWITCHING CHARACTERISTICS (Attribute)**

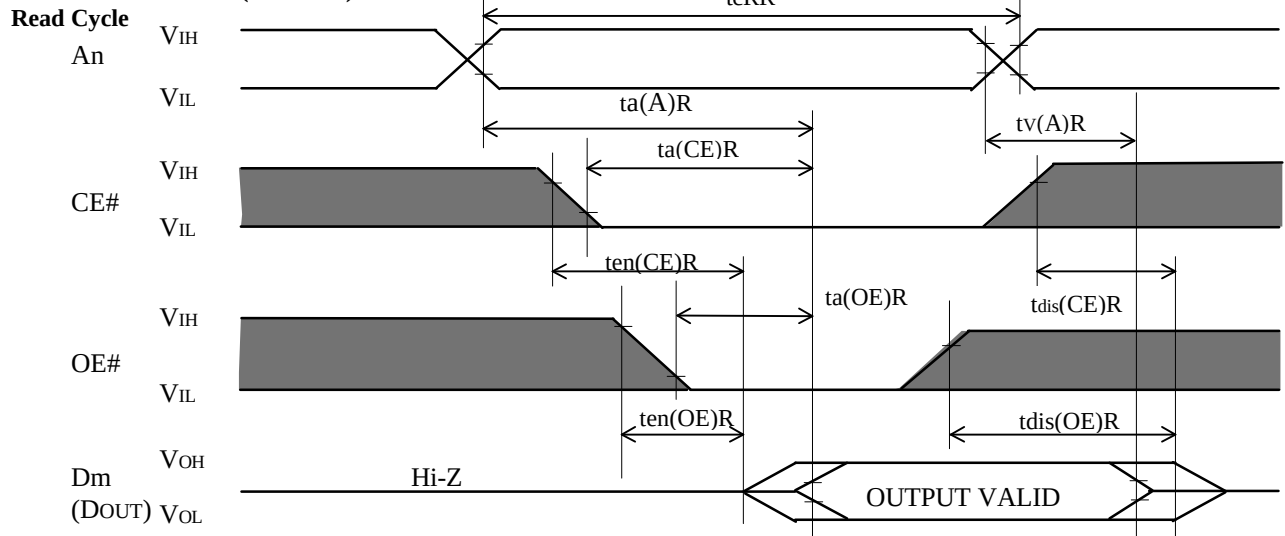
**Read Cycle** ( $T_{\text{a}} = 0 \sim 55^{\circ}\text{C}$ ,  $V_{\text{CC}} = 5\text{V} \pm 5\%$ , unless otherwise noted)

| Symbol                | Parameter                                 | Limits |      | Unit |
|-----------------------|-------------------------------------------|--------|------|------|
|                       |                                           | Min.   | Max. |      |
| $t_{\text{cRR}}$      | Read cycle time                           | 300    |      | ns   |
| $t_{\text{a(A)R}}$    | Address access time                       |        | 300  | ns   |
| $t_{\text{a(CE)R}}$   | Card enable access time                   |        | 300  | ns   |
| $t_{\text{a(OE)R}}$   | Output enable access time                 |        | 150  | ns   |
| $t_{\text{dis(CE)R}}$ | Output disable time (from $\text{CE}\#$ ) |        | 100  | ns   |
| $t_{\text{dis(OE)R}}$ | Output disable time (from $\text{OE}\#$ ) |        | 100  | ns   |
| $t_{\text{en(CE)R}}$  | Output enable time (from $\text{CE}\#$ )  | 5      |      | ns   |
| $t_{\text{en(OE)R}}$  | Output enable time (from $\text{OE}\#$ )  | 5      |      | ns   |
| $t_{\text{V(A)R}}$    | Data valid time after address change      | 0      |      | ns   |



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**TIMING DIAGRAM (Attribute)**



WE#="H" level  
REG#="L" level

**Note 5 : Test Conditions**

Input pulse levels :  $V_{IL}=0.4V$ ,  $V_{IH}=2.8V$

Input pulse rise, fall time :  $t_r=t_f=10ns$

Reference voltage

Input :  $V_{IL}=0.8V$ ,  $V_{IH}=2.4V$

Output :  $V_{OL}=0.8V$ ,  $V_{OH}=2.0V$

(ten and tdis are measured when output voltage is  $\pm 500mV$  from steady state. )

Load :  $100pF + 1$  TTL gate

$5pF + 1$  TTL gate (at ten and tdis measuring)

6 :  Indicates the don't care input

7 : Writing is executed in overlap of CE# and WE# are "L" level. (only for Common Memory)

8 : Don't apply inverted phase signal externally when Dm pin is in output mode.

9 : CE# is indicated as follows:

Read A/Write A : CE#=CE1#-CE2#

Read B/Write B : CE#=CE1#, CE2#="H" level

Read C/Write C : CE#=CE2#, CE1#="H" level



## 18. ELECTRICAL CHARACTERISTICS

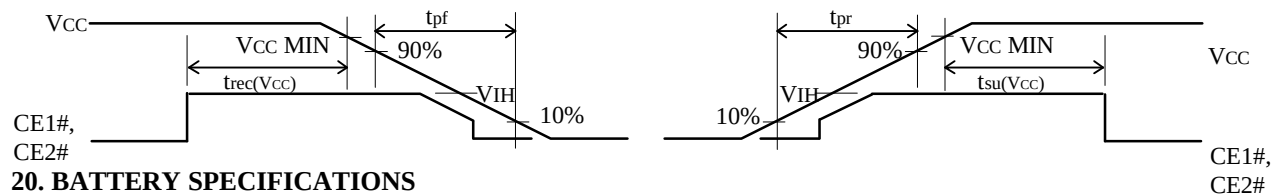
**BATTERY BACKUP** (Ta=0~55°C, unless otherwise noted)

| Symbol       | Parameter                      | Test conditions                        | Limits  |      |         | Unit |
|--------------|--------------------------------|----------------------------------------|---------|------|---------|------|
|              |                                |                                        | Min.    | Typ. | Max.    |      |
| VBATT        | Back-up enable battery voltage | All pins open                          | 2.6     |      |         | V    |
| Vi(CE)       | Card enable voltage            | 2.4V≤VCC≤5.25V                         | 2.4     |      |         | V    |
|              |                                | 0V≤VCC<2.4V                            | Vcc-0.1 | Vcc  | Vcc+0.1 |      |
| Icc<br>(Bup) | Battery back-up supply current | All pins open,<br>VBATT=3V,<br>Ta=25°C | 64KB    |      | 3       | μA   |
|              |                                |                                        | 128KB   |      | 3       |      |
|              |                                |                                        | 256KB   |      | 3       |      |
|              |                                |                                        | 512KB   |      | 5       |      |
|              |                                |                                        | 1MB     |      | 3       |      |
|              |                                |                                        | 2MB     |      | 5       |      |
|              |                                |                                        | 4MB     |      | 9       |      |
|              | Battery back-up supply current | All pins open,<br>VBATT=3V             | 64KB    |      | 30      | μA   |
|              |                                |                                        | 128KB   |      | 30      |      |
|              |                                |                                        | 256KB   |      | 30      |      |
|              |                                |                                        | 512KB   |      | 50      |      |
|              |                                |                                        | 1MB     |      | 30      |      |
|              |                                |                                        | 2MB     |      | 50      |      |
|              |                                |                                        | 4MB     |      | 90      |      |

## 19. TIMING REQUIREMENTS (Ta=0~55°C, unless otherwise noted)

| Symbol    | Parameter                  | Limits |      |      | Unit |
|-----------|----------------------------|--------|------|------|------|
|           |                            | Min.   | Typ. | Max. |      |
| Tpr       | Power supply rise time     | 0.1    |      | 300  | ms   |
| tpf       | Power supply fall time     | 3      |      | 300  | ms   |
| tsu(Vcc)  | Setup time at power on     | 20     |      |      | ms   |
| trec(Vcc) | Recovery time at power off | 1000   |      |      | ns   |

### CARD INSERTION/REMOVAL TIMING DIAGRAM



## 20. BATTERY SPECIFICATIONS

Please use the following coin type lithium battery.

Type of main battery; CR2025 or equivalents

### 20.1 BATTERY LIFE EXPECTANCY

The calculated main battery's life expectancies are as follows.

| Card Type      | main battery's life<br>(when the card is left continuously) |
|----------------|-------------------------------------------------------------|
| MF365A-J9CATXX | 5.9years                                                    |
| MF3129-J9CATXX | 5.9years                                                    |
| MF3257-J9CATXX | 5.9years                                                    |
| MF3513-J9CATXX | 3.6years                                                    |
| MF31M1-J9CATXX | 5.9years                                                    |
| MF32M1-J9CATXX | 3.6years                                                    |
| MF34M1-J9CATXX | 2.0years                                                    |

Conditions; Temperature : 25°C Humidity : 60%RH



## 20.2 REPLACING BATTERY

MF3XXX-J9CATXX series have two batteries inside the card as follows.

Lithium battery; for main battery (replaceable)

Rechargeable battery; for auxiliary battery (not replaceable)

For main battery replacement, perform the following procedure. Performing any other procedures will lose the data recorded in the IC card.

- (1) Have on hand a new main battery that has the same model number as or is equivalent currently installed one.
- (2) Insert the IC card into the system and apply power to the IC card so that the auxiliary battery will be charged.  
(more than 5 minutes)
- (3) While pressing the main battery holder cam release levers inward, slowly withdraw the main battery holder.
- (4) With the new main battery set in the battery holder, insert it completely into the IC card.
- (5) If the battery holder is incorrectly oriented, it will not smoothly fit into its position or the IC card will bulge.  
If such a situation is encountered, properly reorient the battery and battery holder and try again.
- (6) Insert the battery holder until it clicks into position.

### <NOTICE>

Main battery replacement must be completed quickly (recommended time is within 10 minutes).

If too much time is taken, the recorded data may be lost.

The built-in auxiliary battery cannot be replaced.

## 21. CONNECTOR

The number of card insertion and removal are as follows.

|                    |                                             |
|--------------------|---------------------------------------------|
| Office environment | 10000 times min. at speed of 10 cycles/min. |
| Harsh environment  | 5000 times min. at speed of 10 cycles/min.  |

## 22. CARD WEIGHT      about 35g

## 23. UL CLASS OF MAIN CARD PARTS

|                               |         |
|-------------------------------|---------|
| (1) MAIN FRAME                | UL94V-0 |
| (2) PCB                       | UL94V-0 |
| (3) PLASTIC PART OF CONNECTOR | UL94V-0 |

## 24. THE BATTERY VOLTAGE DETECT SIGNALS (BVD1,2)

| BVD1 | BVD2 | Comment                                             |
|------|------|-----------------------------------------------------|
| H    | H    | Battery operational                                 |
| H    | L    | Battery operational, but battery should be replaced |
| L    | L    | Battery and data integrity is not kept              |

Note10. The battery voltage detect signals indicate the present state of the battery.

They do not guarantee the data retention.

## 25. CONCERNING THE SECURITY OF DATA

There is always the possibility that a soft-error (this malfunction is not permanent hence it is called soft and the data can be restored by rewriting) may occur with semiconductor products.

When keeping the important data within an IC card, remember to give due consideration to safety when making your circuit designs, with appropriate measures such as

- (1) Keeping multiple copies of the data.
- (2) Addition of ECC or CRC by software or hardware.



**⚠ Warning ( if card with battery / card with auxiliary battery )**

- (1) Do not charge, short, disassemble, deform, heat, or throw the batteries into fire, as they may ignite, overheat, rupture or explode.
- (2) Place the batteries out of the reach of children. If somebody swallows them, they should see a doctor immediately.
- (3) When discarding or storing the batteries, wrap them individually with cellophane tape or other nonconductive material. If they are positioned in contact with any other metals or batteries, they may explode, rupture or leak electrolyte solution.

**⚠ Caution**

This product is not designed or manufactured for use in a device or system that is used under circumstances in which human life is potentially at stake. Please contact Mitsubishi Electric Corporation or an authorized Mitsubishi Semiconductor product distributor when considering the use of a product contained herein for a special applications, such as apparatus or systems for transportation, vehicular, medical, aerospace, nuclear, or undersea repeater use.

**Keep safety first in your circuit designs!**

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